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(54) **Organic light emitting diode display, touch display device and method for fabricating the same**

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Dispositif d'affichage à diodes électroluminescentes organiques, écran tactile et leur procédé de fabrication

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- **CROPPER A D ET AL: "OPTICAL CHARACTERIZATION OF OLED DISPLAYS WITH TOUCH SCREENS", OPTOMECHATRONIC MICRO/NANO DEVICES AND COMPONENTS III : 8 - 10 OCTOBER 2007, LAUSANNE, SWITZERLAND; PROCEEDINGS OF SPIE, SPIE, BELLINGHAM, WASH, vol. 4464, 1 January 2002 (2002-01-01), pages 344-351, XP008052993, DOI: 10.1117/12.457494 ISBN: 978-1-62841-730-2**

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Description

FIELD OF THE ART

[0001] Embodiments of the invention relate to the field of display technologies, more particularly, to an organic light emitting diode (OLED), a touch display device and a method for fabricating the same.

BACKGROUND

[0002] Flat Panel Display (FPD) devices are widely used due to the advantages of being compact and portable. A main technology for future FPDs is Organic Light Emitting Diode (OLED) display technology. In comparison with Liquid Crystal Display (LCD) technology operated in an overall backlight mode, OLED displays works in a self-luminant mode such that all the pixels in the OLED can emit light. As a result, the OLED displays can notably increase view angles and contrast while reducing power consumption and thickness.

[0003] Touch screens as a modern way of inputting has been used as a main input device in various portable electronic products and are gradually replacing conventional mechanical keypad input device. It is expected that an all-touch non-keypad input mode will be eventually realized in such electronic products. The touch screen technology has undergone various development stages, which mainly includes resistive touch screens, capacitive touch screens, optical sensing touch screens, and electromagnetic sensing touch screens. Currently the mainstream touch screens are the resistive touch screens; however, capacitive touch screens are rapidly catching up. The capacitive touch screens generally include self-capacitance touch screens, surface capacitance touch screen, projected capacitance touch screens and so on.

[0004] On the other hand, conventional touch screens made of OLEDs are mostly add-on capacitive touch screens, which have the disadvantages of having high cost, low touch sensitivity and low reliability.

[0005] JP 2007/147814 A discloses a light emitting device and its manufacturing process. The OLED element has a light-emitting functional layer sandwiched between a common electrode and a pixel electrode. In the circuit region, an auxiliary wiring is arranged between the transistors constituting the peripheral circuit and the light exit surface. The auxiliary wiring is simultaneously formed in the same layer as the pixel electrode.

[0006] US 2008/231168 A1 discloses a display substrate and an organic light emitting diode display device having the same. The display substrate includes a first pixel separating portion and a second pixel separating portion extending from the pixel separating portion and disposed around a pixel portion.

[0007] US 2011/273397 A1 discloses an organic EL display device, which includes a pixel circuit on a first substrate and a touch detection circuit adjacent to the pixel circuit on the first substrate.

SUMMARY

[0008] Embodiments of the invention provide an OLED, a touch display device and a method for fabricating the same, which can improve touch sensitivity of the product and reduce production cost.

[0009] To meet the above objective, the embodiments of the invention provide the following technical solutions.

[0010] An aspect of the invention provides an OLED comprising:

a substrate;
 a pixel electrode functioning as a first conducting electrode on the substrate;
 a first signal electrode and a second signal electrode disposed on the same layer as the pixel electrode;
 an insulating layer overlaying the first signal electrode and the second signal electrode;
 an EL layer overlaying the pixel electrode;
 a second conducting electrode overlaying at least the EL layer; and
 an encapsulating layer overlaying at least the second conducting electrode, wherein a laminated layer formed of the EL layer and the pixel electrode) is in the same layer as the insulating layer and an upper surface of the EL layer (6) is at the same height as an upper surface of the insulating layer.

[0011] As an example, the first conducting electrode is of the organic light emitting diode an anode, and the second conducting electrode is a cathode of the organic light emitting diode.

[0012] As an example, the OLED further comprises a hole transmission layer disposed between the anode and the EL layer.

[0013] As an example, the OLED further comprises an electron transmission layer disposed between the cathode and the EL layer.

[0014] As an example, the insulating layer is an organic insulating layer.

[0015] As an example, a portion of the second conducting electrode correspondingly located above the first signal electrode and the second signal electrode is removed.

[0016] A second aspect of the invention provides a method for fabricating an organic light emitting diode comprising:

forming a first conducting film on a substrate;
 forming a pixel electrode as well as a first signal electrode and a second signal electrode through a single patterning process, wherein the pixel electrode functions as a first conducting electrode;
 forming an insulating layer overlaying the pixel electrode as well as the first signal electrode and the second signal electrode;
 forming a via hole in the insulating layer above the pixel electrode;

forming an EL layer in the via hole;
 forming a second conducting film overlaying the EL layer and the insulating layer, wherein the second conducting film functions as a second conducting electrode;
 forming an encapsulating layer overlaying at least the second conducting electrode; wherein a laminated layer formed of the EL layer and the pixel electrode is in the same layer as the insulating layer, an upper surface of the EL layer (6) is at the same height as an upper surface of the insulating layer.

[0017] As an example, the method further comprises performing a patterning process on the second conducting electrode to remove the portion of the second conducting electrode located directly above the first signal electrode and the second signal electrode.

[0018] As an example, the method further comprises forming a hole transmission layer between the first conducting electrode and the EL layer, and forming an electron transmission layer between the second conducting electrode and the EL layer.

[0019] A third aspect of the invention provides a touch display device comprising: a plurality of display elements arranged in an array, wherein each of the display elements comprises a pixel element surrounded by a gate line and a data line, and the pixel elements comprises any of the above-described OLED.

[0020] As an example, the touch display device further comprises a plurality of first sensing lines arranged parallel to each other and a plurality of second sensing lines arranged parallel to each other, the first sensing lines and the second sensing lines intersect with each other but are not electrically connected with each other, the first signal electrode of the OLED is electrically connected to the first sensing lines, the second signal electrode of the OLED is electrically connected to the second sensing lines.

[0021] As an example, the first sensing lines are in the same layer as the data line, the second sensing lines are in the same layer as the gate line.

[0022] As an example, the first sensing lines are in the same layer as the gate line, the second sensing lines are in the same layer as the data line.

[0023] A fourth aspect of the invention provides a method for fabricating a touch display device comprising:

forming a metal conducting film on a substrate and forming a gate electrode, a gate line and a longitudinal sensing line through a patterning process;
 forming a gate insulating layer overlaying the substrate;
 forming an active layer on the gate insulating layer;
 forming a metal conducting film on the substrate and forming a source electrode, a drain electrode, a data line and a transversal sensing line through a patterning process;
 forming a passivation layer overlaying the substrate;

forming via holes going through the passivation layer above the drain electrode, the transversal sensing line and the longitudinal sensing line;
 forming a first conducting film on the passivation layer and forming a pixel electrode functioning as a first conducting electrode as well as a first signal electrode and a second signal electrode through a single patterning process, wherein the pixel electrode is electrically connected to the drain electrode through the via hole above the drain electrode, the first signal electrode is electrically connected to the transversal sensing line through the via hole above the transversal sensing line, the second signal electrode is electrically connected to the longitudinal sensing line through the via hole above the longitudinal sensing line;
 forming an insulating layer overlaying the pixel electrode as well as the first signal electrode and the second signal electrode;
 forming a via hole in the insulating layer above the pixel electrode;
 forming an EL layer in the via hole (2) such that a laminated layer of the EL layer (6) and the pixel electrode (2) is in the same layer as the insulating layer (5) and an upper surface of the EL layer (6) is at the same height as an upper surface of the insulating layer (5);
 forming a second conducting film overlaying the EL layer and the insulating layer, wherein the second conducting film functions as a second conducting electrode;
 forming an encapsulating layer overlaying at least the second conducting electrode.

[0024] As an example, the method further comprises performing a patterning process on the second conducting electrode to remove the portion of the second conducting electrode located directly above the first signal electrode and the second signal electrode.

[0025] As an example, the method further comprises:

forming a hole transmission layer between the first conducting electrode and the EL layer; and
 forming an electron transmission layer between the second conducting electrode and the EL layer.

BRIEF DESCRIPTION OF THE DRAWINGS

[0026] In order to clearly illustrate the technical solution of the embodiments of the invention, the drawings of the embodiments will be briefly described in the following; it is obvious that the described drawings are only related to some embodiments of the invention and thus are not limitative of the invention.

Fig. 1 schematically illustrates a top view of an OLED in accordance with an embodiment of the invention; Fig. 2 schematically illustrates a cross section of the

OLED taken along line A-A' of Fig. 1 in accordance with the embodiment of the invention;
 Fig. 3 schematically illustrates a cross section of the OLED taken along line B-B' of Fig. 1 in accordance with the embodiment of the invention;
 Fig. 4 is an equivalent circuit of a projected capacitance of the OLED in accordance with the embodiment of the invention;
 Fig. 5 is an equivalent circuit of a projected capacitance of the OLED when being touched in accordance with the embodiment of the invention;
 Fig. 6 is an equivalent circuit of a projected capacitance of an OLED when being touched in accordance with another embodiment of the invention;
 Fig. 7 schematically illustrates a flow chart of a method for fabricating an OLED in accordance with an embodiment of the invention;
 Fig. 8 schematically illustrates a top view of a touch screen device in accordance with an embodiment of the invention;
 Fig. 9 schematically illustrates a cross section of the touch screen device taken along line C-C' of Fig. 7 in accordance with an embodiment of the invention;
 Fig. 10 schematically illustrates a flow chart of a method for fabricating a touch screen device in accordance with an embodiment of the invention;
 Fig. 11 schematically illustrates a hole transmission layer and an electron transmission layer of a touch screen device not forming part of the invention.

DETAILED DESCRIPTION

[0027] In order to make objects, technical details and advantages of the embodiments of the invention apparent, the technical solutions of the embodiment will be described in a clearly and fully understandable way in connection with the drawings related to the embodiments of the invention. It is obvious that the described embodiments are just a part but not all of the embodiments of the invention. Based on the described embodiments herein, those skilled in the art can obtain other embodiment(s), without any inventive work, which should be within the scope of the invention.

[0028] Unless otherwise defined, all the technical and scientific terms used herein have the same meanings as commonly understood by one of ordinary skill in the art to which the present invention belongs. The terms "first," "second," etc., which are used in the description and the claims of the present application for invention, are not intended to indicate any sequence, amount or importance, but distinguish various components. Also, the terms such as "a," "an," etc., are not intended to limit the amount, but indicate the existence of at least one. The terms "comprises," "comprising," "includes," "including," etc., are intended to specify that the elements or the objects stated before these terms encompass the elements or the objects and equivalents thereof listed after these terms, but do not preclude the other elements or objects.

The phrases "connect", "connected", etc., are not intended to define a physical connection or mechanical connection, but may include an electrical connection, directly or indirectly. "On," "under," "right," "left" and the like are only used to indicate relative position relationship, and when the position of the object which is described is changed, the relative position relationship may be changed accordingly.

[0029] As illustrated in Figs. 1, 2 and 3 (in which Fig. 2 is a cross section of an OLED taken along line A-A' of Fig. 1 and Fig. 3 is a cross section of the OLED taken along line B-B' of Fig. 1), the OLED as provided by an embodiment of the invention comprises:

[0030] a substrate 1; a pixel electrode 2 functioning as a first conducting electrode on the substrate 1, a first signal electrode 3 and a second signal electrode 4 disposed on the same layer as the pixel electrode 2. The first signal electrode 3 is used for connecting a first sensing line which extends longitudinally and the second signal electrode 4 is used for connecting a second sensing line which extends transversally, the first sensing line and the second sensing line intersect with each other but are not electrically connected (the first and second sensing lines are not illustrated in the figures) with each other; an insulating layer 5 overlaying the first signal electrode 3 and the second signal electrode 4, an electroluminescent (EL) layer 6 overlaying the pixel electrode 2, a laminated layer of the EL layer 6 and the pixel electrode 2 is in the same layer as the insulating layer 5 (that is, an upper surface of the EL layer 6 is at the same height as an upper surface of the insulating layer 5, as shown in Fig. 3); a second conducting electrode 7 overlaying at least the EL layer 6; and an encapsulating layer 8 overlaying at least the second conducting electrode 7.

[0031] Those skilled in the art would understand that the drawings are illustrative only. Moreover, the terms "longitudinally", "longitudinal", "transversally" and "transversal" are only used to illustrate relative position relationship of the first sensing line and the second sensing line. Therefore, it can be understood that if the first sensing line is a longitudinal sensing line then the second sensing line is a transversal sensing line; on the contrary, if the first sensing line is a transversal sensing line then the second sensing line is a longitudinal sensing line. As for positions in the planar view as illustrated in Fig. 1, the first signal electrode 3 may be disposed above or below the second signal electrode 4.

[0032] Optionally, the first conducting electrode, i.e., the pixel electrode 2, is an anode of an OLED, and the second conducting electrode 7 is a cathode of the OLED. The OLED further comprising a hole transmission layer disposed between the anode and the EL layer and an electron transmission layer disposed between the cathode and the EL layer.

[0033] The insulating layer 5 may be an organic insulating layer.

[0034] In the embodiment, the second conducting electrode 7 forms projected capacitors with the first signal

electrode 3 and the second signal electrode 4 respectively, with an equivalent circuit as shown in Fig. 4, where C_X indicates a capacitor formed between the second conducting electrode 7 and the first signal electrode 3, C_Y indicates a capacitor formed between the second conducting electrode 7 and the second signal electrode 4, C_{XY} indicates a capacitor formed between the first signal electrode 3 and the second signal electrode 4. When a finger touches the encapsulating layer 8 above the second conducting electrode 7, a capacitor C_F is formed between the finger and the second conductor electrode 7, with an equivalent circuit as illustrated in Fig. 5. The cathode of the OLED (i.e. the second conducting electrode 7) provides a DC voltage signal which remains constant, therefore, when the overall capacitance changes due to the introduction of the capacitor C_F, that is, the equivalent circuit changes from Fig. 4 to Fig. 5, voltage signals on the first signal electrode 3 and the second signal electrode 4 are changed (this is because the finger can be seen as the ground, in this case, charges on the capacitors C_X and C_Y will be charged to the capacitor C_F, thereby changing the voltage on the first signal electrode 3 and the second signal electrode 4). This principle can be used to determine whether the OLED is being touched.

[0035] Furthermore, a portion of the second conducting electrode 7 located directly above the first signal electrode 3 and the second signal electrode 4 is removed (which is not illustrated in the figures), such that the encapsulating layer 8 is formed directly on the insulating layer 5 above the first signal electrode 3 and the second signal electrode 4 (i.e., formed in the removed portion of the second conducting electrode 7). In this case, no capacitor is formed between the second conducting electrode 7 and the first signal electrode 3 as well as the second signal electrode 4. When touched, due to that an area of a touching object is generally larger than an area of the a single pixel element, the touching object forms capacitors with the first signal electrode 3 and the second signal electrode 4 respectively, with an equivalent circuit as illustrated in Fig. 6 (in which the touching object is exemplarily illustrated as a finger), where C_M indicates a capacitor formed between the finger and the first signal electrode 3, C_N indicates a capacitor formed between the finger and the second signal electrode 4, and C_{MN} indicates a capacitor formed between the first signal electrode 3 and the second signal electrode 4. The touch changes the current signals on the first signal electrode 3 and the second signal electrode 4, which can be used to determine whether the OLED is being touched.

[0036] With the OLED provided by the embodiment of the invention, the projected capacitance used for touch is simultaneously formed during the fabrication of the OLED, two separate signal sensing elements in the longitudinal and transversal directions are formed for each of pixel elements, which can improve the touch sensitivity of the product. Moreover, the product cost is reduced due to the signal electrodes as the projected capacitance and

the pixel electrode of the LED are formed in the same layer.

[0037] As illustrated in Fig. 7, an embodiment of the invention provides a method for fabricating an OLED. Generally, the fabrication method comprises a step of forming a first and a second electrode layers and an EL layer sandwiched between the first and second electrode layers as well as a step of forming a first and a second signal electrodes and an insulating layer. As an example, the method comprises the following steps:

S101: forming a first conducting film layer on a substrate;

S102: forming a pixel electrode functioning as a first conducting electrode as well as a first signal electrode and a second signal electrode through a single patterning process.

[0038] For example, a first conducting film layer may be formed on the whole surface of a substrate, the first conducting film is made from conducting material with a thickness of 100Å to 1000Å. Then, a layer of photoresist is applied on the first conducting film, and the pixel electrode, the first signal electrode and the second electrode are formed by using a mask to perform patterning processes including exposing, developing, etching and peeling.

[0039] S103: forming an insulating layer overlaying the pixel electrode as well as the first signal electrode and the second signal electrode.

[0040] For example, an insulating layer with a thickness of 1000Å to 6000Å may be continuously deposited on the substrate using Chemical Evaporation Deposition (CVD). The insulating layer is for example an organic insulating layer and the layer may be formed through conventional method, such as deposition, spin-coating or roller coating.

[0041] S104: forming a via hole in the insulating layer above the pixel electrode.

[0042] S105: forming an EL layer in the via hole.

[0043] For example, the substrate is placed in a vacuum chamber and multiple organic films are deposited above the pixel electrode to form the EL layer, where an average thickness of the films is 350Å±25Å.

[0044] Optionally, it may further comprising the following before step S105: forming a hole transmission layer between the first conducting electrode and the EL layer, and a material of the hole transmission layer is for example aromatic diamine, such as N,N,N', N'-tetraphenyl-1, 1'-biphenyl-4, 4'-diamine (TPD), C₇₃H₅₂N₄ (TAD) and the like.

[0045] Optionally, it may further comprising the following after step S105: forming an electron transmission layer between the second conducting electrode and the EL layer, and a material of the electron transmission layer is for example 8-hydroxyquinoline aluminum (Alq3), 8-hydroxyquinoline zinc (Znq2) and the like.

[0046] S106: forming a second conducting film over-

laying the EL layer and the insulating layer as a second conducting electrode.

[0047] It is noted that when an electron transmission layer is formed between the second conducting electrode and the EL layer, the second conducting electrode formed in step S106 overlays the electron transmission layer.

[0048] Optionally, the step S106 may further comprising: performing a patterning process on the second conducting electrode to remove the portion of the second conducting electrode located directly above the first and second signal electrodes. An equivalent circuit of the OLED formed with this optional step is illustrated in Fig. 6. The optional step can also be performed with the patterning process for forming the second conducting electrode and no additional exposing process is required.

[0049] S107: forming an encapsulating layer overlaying the second conducting electrode.

[0050] In the method for fabricating the OLED as provided by the embodiment of the invention, the projected capacitance used for touch is simultaneously formed during the fabrication of the OLED, two separate signal sensing elements in the longitudinal and transversal directions are formed for each of pixel elements, which can improve the touch sensitivity of the product. Moreover, the product cost is reduced due to the signal electrodes as the projected capacitance and the pixel electrode of the LED are formed in the same layer.

[0051] Another embodiment of the invention further provides a touch display device as illustrated in Figs. 8 and 9 (Fig. 9 schematically illustrates a cross section of the touch display device taken along line C-C' of Fig. 8), which comprises: a plurality of display elements arranged in an array, and each display element comprises a pixel element surrounded by a gate line and a data line, pixel elements of at least a part of the display elements comprise the OLED provided by the above embodiment. The touch display device further comprising a plurality of first sensing lines 14 arranged parallel to each other and a plurality of second sensing lines 15 arranged parallel to each other, the first sensing lines 14 and the second sensing lines 15 intersect with each other but are not electrically connected to each other. A first signal electrode 16 of the OLED is electrically connected to the first sensing lines 14, a second signal electrode 17 of the OLED is electrically connected to the second sensing lines 15. Preferably, the first signal electrode 16 is electrically connected to the first sensing lines 14 through a via hole, and the second signal electrode 17 is electrically connected to the second sensing lines 15 through another via hole.

[0052] Generally, each pixel element may further comprising a TFT on a substrate 11, a passivation layer 13 overlaying the TFT, an OLED electrically connected to a drain electrode of the TFT through a via hole of the passivation layer 13. The pixel electrode of the OLED, which functioning as the first conducting electrode, is connected to the drain electrode.

[0053] Optionally, the first sensing line is in the same layer as the data line, the second sensing line is in the same layer as the gate line. That is, the first sensing line is disposed between the passivation layer 13 and the gate insulating layer 12 overlaying the gate of the TFT, the second sensing line is disposed between the substrate 11 and the gate insulating layer 12.

[0054] Alternatively, the first sensing line is in the same layer as the gate line, the second sensing line is in the same layer as the data line. That is, the second sensing line is disposed between the passivation layer and the gate insulating layer overlaying the gate of the TFT, the first sensing line is disposed between the substrate and the gate insulating layer (not shown in the figure).

[0055] According to the working principle of the OLED with the projected capacitance provided by the embodiment of the invention, due to that the first and second sensing lines intersect with each other but are not electrically connected with each other, when a touch happens above the cathode, the two sensing lines can generate voltage variation signals on the first and the second signal electrodes in the longitudinal and transversal directions (for example, in the X and Y directions) which are vertical to each other, thereby locating the touch position.

[0056] In the touch display device provided by the embodiment of the invention, the projected capacitance used for touch is simultaneously formed during the fabrication of the OLED, two separate signal sensing elements in the longitudinal and transversal directions are formed for each pixel elements, which can improve the touch sensitivity of the product. Moreover, the product cost is reduced due to the signal electrodes as the projected capacitance and the pixel electrode of the LED are formed in the same layer.

[0057] Furthermore, each display element of the embodiment may comprise three pixel elements of red, green and blue. The display element can surely have more pixel elements of other colors, though an example of a pixel element having three primitive colors of red, green and blue will be described exemplarily. Preferably, the OLED provided by the embodiment of the invention is selectively disposed in the three pixel elements of red, green and blue included in the display element. When the three pixel elements of red, green and blue have the same light-emitting area, brightness may differ from each other. As a result, the light-emitting areas of the three pixel elements of red, green and blue are configured proportionally to ensure the uniformity of the light-emitting brightness. As an example, for pixel elements with the same light-emitting area, a green light-emitting material produces a higher brightness. Therefore, the area of the EL layer of the green pixel element is generally reduced during fabrication. More preferably, the OLED provided by the embodiment of the invention is configured in the green pixel element. By this means, even if the signal electrode for forming the projected capacitance takes up a certain light-emitting area in the pixel electrode layer of the OLED, the influence on the brightness of the dis-

play device can be minimized. Naturally, it is also feasible for the red or blue pixel element to employ the OLED provided by the embodiment of the invention. More preferably, among all the green pixel elements, it may choose to dispose the touch capacitor in some of them according to actual requirements, such as resolution, sensing area and capacitor sensitivity and so on. That is, the number and position relationship of green pixel elements with the touch capacitor and those without the touch capacitor may be determined according to actual requirements.

[0058] Another embodiment of the invention provides a method for fabricating a touch display device. Generally, the fabrication method comprises a step of forming a first and a second electrode layers and an EL layer sandwiched between the first and second electrode layers, a step of forming a data line and a gate line as well as a step of forming a first and a second signal electrodes and an insulating layer. As an example, as illustrated in Fig. 10, the method comprises the following steps:

[0059] S201: forming a metal conducting film on a substrate and forming a gate electrode, a gate line and a longitudinal sensing line through a patterning process.

[0060] For example, a layer of metal conducting film with a thickness of 1000Å to 7000Å may be formed on a substrate by using magnetron sputtering. A metal material for fabricating the metal conducting film generally may be molybdenum, aluminum, aluminum nickel alloy, molybdenum tungsten alloy, chrome, copper etc. The metal conducting film may be a laminated film layer made of the above materials. Then, the gate electrode, the gate line and the longitudinal sensing line are formed on a certain area on the substrate by using a mask to perform patterning processes including exposing, developing, etching and peeling. The metal conducting films may be formed by means of Plasma Enhanced Chemical Vapor Deposition (PECVD), magnetron sputtering, thermal evaporation and other conventional method for fabricating film.

[0061] S202: forming a gate insulating layer overlaying the substrate.

[0062] For example, a film of a gate insulating layer with a thickness of 1000Å to 6000Å is continuously deposited on the substrate by using CVD. A material of the gate insulating layer is generally silicon nitride, but can also be silicon oxide and silicon oxynitride. The film of the gate insulating layer may be formed by conventional fabricating method, such as, deposition, spin-coating or roller-coating.

[0063] S203: forming an active layer on the gate insulating layer.

[0064] For example, an amorphous silicon (a-Si) film and an n⁺ amorphous silicon film with a total thickness of 1000Å to 6000Å may be deposited on the gate insulating layer using CVD. Alternatively, a metal oxide semiconductor film may be deposited on the gate insulating layer. A mask for the active layer may be used to expose the a-Si film, which is then dry etched to form an active layer on the gate insulating layer. Furthermore, if it is the

metal oxide semiconductor film that is deposited on the gate insulating layer as the active layer, then the active layer may be formed through a patterning process on the metal oxide semiconductor film. That is, after applying photoresist, a mask may be used to expose, develop and etch the metal oxide semiconductor film to form the active layer.

[0065] S204: forming a metal conducting film on the substrate and then forming a source electrode, a drain electrode, a data line and a transversal sensing line through a patterning process.

[0066] For example, similar to the method of fabricating the gate electrode, a metal conducting film with a thickness of 1000Å to 7000Å may be formed on the substrate. A metal material for fabricating the metal conducting film generally may be molybdenum, aluminum, aluminum nickel alloy, molybdenum tungsten alloy, chrome, copper etc. The metal conducting film may be a laminated film layer made of the above materials. Then, the source electrode, the drain electrode, the data line and the transversal sensing line are formed by using a mask to perform patterning processes including exposing, developing, etching and peeling. The films may be formed by means of PECVD, magnetron sputtering, thermal evaporation and other conventional method for fabricating film.

[0067] S205: forming a passivation layer overlaying the substrate.

[0068] For example, a passivation layer with a thickness of 1000Å to 6000Å is deposited on the whole surface of the substrate. A material of the passivation layer may be oxide such as silicon dioxide. In this case, the passivation layer overlays the gate electrode, the source electrode, the drain electrode, the second sensing line or the first sensing line.

[0069] S206: forming via holes going through the passivation layer above the drain electrode, the transversal sensing line and the longitudinal sensing line respectively.

[0070] S207: forming a layer of first conducting film on the passivation layer and forming a pixel electrode functioning as a first conducting electrode as well as a first signal electrode and a second signal electrode through a single patterning process.

[0071] The pixel electrode is electrically connected to the drain electrode through the via hole above the drain electrode, the first signal electrode is electrically connected to a first sensing line through the via hole above the first sensing line, a second signal electrode is electrically connected to the second sensing line through the via hole above the second sensing line. The first sensing line is the transversal sensing line and the second sensing line is the longitudinal sensing line. Alternatively, the second sensing line is the transversal sensing line and the first sensing line is the longitudinal sensing line. It can be understood that the terms "longitudinal" and "transversal" means relative positions and only used to illustrate relative position relationship of the first sensing line and the second sensing line. Therefore, it can be understood that

if the first sensing line is a longitudinal sensing line then the second sensing line is a transversal sensing line; on the contrary, if the first sensing line is a transversal sensing line then the second sensing line is a longitudinal sensing line.

[0072] For steps following S207 please refer to S101 to S107, which will not be elaborated here.

[0073] S208: forming an insulating layer overlaying the pixel electrode as well as the first signal electrode and the second signal electrode.

[0074] S209: forming a via hole in the insulating layer above the pixel electrode.

[0075] S210: forming an EL layer in the via hole.

[0076] For example, the substrate is placed in a vacuum chamber and multiple organic films are deposited above the pixel electrode to form the EL layer, where an average thickness of the films is $350\text{\AA} \pm 25\text{\AA}$.

[0077] Optionally, it may further comprising the following before step S210: forming a hole transmission layer between the first conducting electrode and the EL layer, and a material of the hole transmission layer is for example aromatic diamine, such as N,N,N', N'-tetraphenyl-1, 1'-biphenyl-4, 4'-diamine (TPD), $C_{73}H_{52}N_4$ (TAD) and the like.

[0078] It may further comprising the following after step S210: forming an electron transmission layer between the second conducting electrode and the EL, where a material of the electron transmission layer is 8-Hydroxyquinoline aluminum (Alq3), 8-Hydroxyquinoline zinc (Znq2) and the like.

[0079] S211: forming a second conducting film overlaying the EL layer and the insulating layer as a second conducting electrode.

[0080] It is noted that when an electron transmission layer is formed between the second conducting electrode and the EL layer, the second conducting electrode formed in step S211 overlays the electron transmission layer.

[0081] Optionally, step S211 may further comprising: performing a patterning process on the second conducting electrode to remove the portion of the second conducting electrode located directly above the first and second signal electrodes. An equivalent circuit of the OLED formed with this optional step is illustrated in Fig. 6. The optional step can also be performed with the patterning process for forming the second conducting electrode and no additional exposing process is required.

[0082] S212: forming an encapsulating layer overlaying the second conducting electrode.

[0083] In the method for fabricating the touch display device as provided by the embodiment of the invention, the projected capacitance used for touch is simultaneously formed during the fabrication of the OLED, two separate signal sensing elements in the longitudinal and transversal directions are formed for each pixel elements, which may improves the sensitivity of the touch screen product. Moreover, the product cost is reduced due to the signal electrodes as the projected capacitance and

the pixel electrode of the LED are formed in the same layer.

[0084] What are described above is related to the illustrative embodiments of the disclosure only and not limitative to the scope of the disclosure; the scopes of the disclosure are defined by the accompanying claims.

Claims

1. An organic light emitting diode, comprising:

a substrate (1);
 a pixel electrode (2) functioning as a first conducting electrode on the substrate (1);
 a first signal electrode (3) and a second signal electrode (4) disposed on the same layer as the pixel electrode (2);
 an insulating layer (5) overlaying the first signal electrode (3) and the second signal electrode (4);
 an electroluminescent layer (EL) (6) overlaying the pixel electrode (2), a laminated layer of the EL layer (6) and the pixel electrode (2) is in the same layer as the insulating layer (5);
 a second conducting electrode (7) overlaying at least the EL layer (6); and
 an encapsulating layer (8) overlaying at least the second conducting electrode (7);
characterizing in that an upper surface of the EL layer (6) is at the same height as an upper surface of the insulating layer (5).

2. The organic light emitting diode of claim 1, wherein the first conducting electrode (3) is an anode of the organic light emitting diode, and the second conducting electrode (4) is a cathode of the organic light emitting diode.

3. The organic light emitting diode of claim 2, further comprising a hole transmission layer disposed between the anode and the EL layer (6).

4. The organic light emitting diode of claim 2, further comprising an electron transmission layer disposed between the cathode and the EL layer (6).

5. The organic light emitting diode of claim 1, wherein the insulating layer (5) is an organic insulating layer.

6. The organic light emitting diode of any of claims 1 to 5, wherein a portion of the second conducting electrode (7) located directly above the first signal electrode (3) and the second signal electrode (4) is removed such that the encapsulation layer (8) may be formed directly on the insulating film (5) above the first signal electrode (3) and the second signal electrode (4).

7. A method for fabricating an organic light emitting diode comprising:

forming a first conducting film on a substrate (1);
forming a pixel electrode (2) as well as a first
signal electrode (3) and a second signal elec-
trode (4) through a single patterning process,
wherein the pixel electrode (2) functions as a
first conducting electrode;
forming an insulating layer (5) overlaying the pixel
electrode (2) as well as the first signal electrode
(3) and the second signal electrode (4);
forming a via hole in the insulating layer (5)
above the pixel electrode (2);
forming an electroluminescent layer (EL) (6) in
the via hole such that a laminated layer of the
EL layer (6) and the pixel electrode (2) is in the
same layer as the insulating layer (5);
forming a second conducting film overlaying the
EL layer (6) and the insulating layer (5), wherein
the second conducting film functions as a second
conducting electrode (7);
forming an encapsulating layer (8) overlaying at
least the second conducting electrode (7);
characterizing in that an upper surface of the
EL layer (6) is at the same height as an upper
surface of the insulating layer (5).

8. The method of claim 7, further comprising: perform-
ing a patterning process on the second conducting
electrode (7) to remove the portion of the second
conducting electrode (7) located directly above the
first signal electrode (3) and the second signal elec-
trode (4).

9. The method of claim 7 or 8, further comprising: form-
ing a hole transmission layer between the first con-
ducting electrode (3) and the EL layer (6), and form-
ing an electron transmission layer between the sec-
ond conducting electrode (4) and the EL layer (6).

10. A touch display device comprising: a plurality of dis-
play elements arranged in an array, wherein each of
the display elements comprises a pixel element sur-
rounded by a gate line and a data line, and the pixel
elements comprises the OLED of any of claims 1 to 6.

11. The touch display device of claim 10, further com-
prising: a plurality of first sensing lines (14) arranged
parallel to each other and a plurality of second sens-
ing lines (15) arranged parallel to each other, the first
sensing lines (14) and the second sensing lines (15)
intersect with each other but are not electrically con-
nected with each other, the first signal electrode (16)
of the OLED is electrically connected to the first sens-
ing lines (14), the second signal electrode (17) of the
OLED is electrically connected to the second sens-
ing lines (15).

12. The touch display device of claim 11, wherein the
first sensing lines (14) are in the same layer as the
data line, the second sensing lines (15) are in the
same layer as the gate line.

13. The touch display device of claim 11, wherein the
first sensing lines (14) are in the same layer as the
gate line, the second sensing lines (15) are in the
same layer as the data line.

14. A method for fabricating a touch display device com-
prising:

forming a metal conducting film on a substrate
(11) and forming a gate electrode, a gate line
and a longitudinal sensing line through a pat-
tarning process;
forming a gate insulating layer (12) overlaying
the substrate (11);
forming an active layer on the gate insulating
layer (12);
forming a metal conducting film on the substrate
(11) and forming a source electrode, a drain
electrode, a data line and a transversal sensing
line through a patterning process;
forming a passivation layer (13) overlaying the
substrate (11);
forming via holes going through the passivation
layer (13) above the drain electrode, the trans-
versal sensing line and the longitudinal sensing
line;
forming a first conducting film on the passivation
layer (13) and forming a pixel electrode func-
tioning as a first conducting electrode as well as a
first signal electrode (16) and a second signal
electrode (17) through a single patterning proc-
ess, wherein the pixel electrode is electrically
connected to the drain electrode through the via
hole above the drain electrode, the first signal
electrode (16) is electrically connected to the
transversal sensing line through the via hole
above the transversal sensing line, the second
signal electrode (17) is electrically connected to
the longitudinal sensing line through the via hole
above the longitudinal sensing line;
forming an insulating layer overlaying the pixel
electrode as well as the first signal electrode (16)
and the second signal electrode (17);
forming a via hole in the insulating layer above
the pixel electrode;
forming an electroluminescent layer (EL) (6) in
the via hole such that a laminated layer of the
EL layer (6) and the pixel electrode (2) is in the
same layer as the insulating layer (5) and an
upper surface of the EL layer (6) is at the same
height as an upper surface of the insulating layer
(5);
forming a second conducting film overlaying the

EL layer and the insulating layer, wherein the second conducting film functions as a second conducting electrode;
forming an encapsulating layer overlaying at least the second conducting electrode.

15. The method of claim 14, further comprising: performing a patterning process on the second conducting electrode to remove the portion of the second conducting electrode located directly above the first signal electrode and the second signal electrode.

16. The method of claim 14 or 15, further comprising:

forming a hole transmission layer between the first conducting electrode and the EL layer; and forming an electron transmission layer between the second conducting electrode and the EL layer.

Patentansprüche

1. Organische lichtemittierende Diode, umfassend:

ein Substrat (1);
eine Pixelelektrode (2), funktionierend als eine erste leitfähige Elektrode auf dem Substrat (1);
eine erste Signalelektrode (3) und eine zweite Signalelektrode (4), angeordnet auf der gleichen Schicht wie die Pixelelektrode (2);
eine die erste Signalelektrode (3) und die zweite Signalelektrode (4) überlagernde Schicht (5);
eine die Pixelelektrode (2) überlagernde Elektrolumineszenz-Schicht (EL), wobei eine laminierte Schicht der EL-Schicht (6) und der Pixelelektrode (2) in der gleichen Schicht wie die isolierende Schicht (5) ist;
eine zumindest die EL-Schicht (6) überlagernde zweite leitfähige Elektrode (7); und
eine zumindest die zweite leitfähige Elektrode (7) abkapselnde Schicht (8);
dadurch gekennzeichnet, dass eine obere Oberfläche der EL-Schicht (6) bei dem gleichen Niveau wie eine obere Oberfläche der isolierenden Schicht (5) ist.

2. Organische lichtemittierende Diode gemäß Anspruch 1, wobei die erste leitfähige Elektrode (3) eine Anode der organischen lichtemittierenden Diode ist und wobei die zweite leitfähige Elektrode (4) eine Kathode der organischen lichtemittierenden Diode ist.

3. Organische lichtemittierende Diode gemäß Anspruch 2, außerdem umfassend eine Lochübertragungsschicht, angeordnet zwischen der Anode und der EL-Schicht (6).

4. Organische lichtemittierende Diode gemäß Anspruch 2, außerdem umfassend eine Elektronenübertragungsschicht, angeordnet zwischen der Kathode und der EL-Schicht (6).

5. Organische lichtemittierende Diode gemäß Anspruch 1, wobei die isolierende Schicht (5) eine organische isolierende Schicht ist.

6. Organische lichtemittierende Diode gemäß einem der Ansprüche 1 bis 5, wobei ein Bereich der zweiten leitfähigen Elektrode (7), der direkt oberhalb der ersten Signalelektrode (3) und der zweiten Signalelektrode (4) lokalisiert ist, entfernt ist, so dass die abkapselnde Schicht (8) direkt auf dem isolierenden Film (5) oberhalb der ersten Signalelektrode (3) und der zweiten Signalelektrode (4) gebildet sein kann.

7. Verfahren zur Herstellung einer organischen lichtemittierenden Diode, umfassend:

Bilden eines ersten leitfähigen Films auf dem Substrat (1);

Bilden einer Pixelelektrode (2) sowie einer ersten Signalelektrode (3) und einer zweiten Signalelektrode (4) durch einen einzelnen Bemusterungsprozess, wobei die Pixelelektrode (2) als eine erste leitfähige Elektrode wirkt;

Bilden einer die erste Elektrode (2) sowie die erste Signalelektrode (3) und die zweite Signalelektrode (4) überlappenden isolierenden Schicht (5);

Bilden einer Durchgangsöffnung in der isolierenden Schicht (5) oberhalb der Pixelelektrode (2);

Bilden einer Elektrolumineszenz-Schicht (EL) (6) in der Durchgangsöffnung, so dass sich eine laminierte Schicht der EL-Schicht (6) und die Pixelelektrode (2) in der gleichen Schicht wie die isolierende Schicht (5) befinden;

Bilden einer die EL-Schicht (6) und die isolierende Schicht (5) überlagernden zweiten leitfähigen Films, wobei der zweite leitfähige Film als eine zweite leitfähige Elektrode (7) wirkt;

Bilden einer zumindest die zweite leitfähige Elektrode (7) überlagernden Schicht (8);

dadurch gekennzeichnet, dass eine obere Oberfläche der EL-Schicht (6) auf dem gleichen Niveau wie eine obere Oberfläche der isolierenden Schicht (5) ist.

8. Verfahren gemäß Anspruch (7), außerdem umfassend: Durchführen eines Bemusterungsprozesses auf der zweiten leitfähigen Elektrode (7), um den Bereich der zweiten leitfähigen Elektrode (7), der direkt oberhalb der ersten Signalelektrode (3) und der zweiten Signalelektrode (4) lokalisiert ist, zu entfernen.

9. Verfahren gemäß Anspruch 7 oder 8, außerdem umfassend: Bilden einer Lochübertragungsschicht zwischen der ersten leitfähigen Elektrode (3) und der EL-Schicht (6) und Bilden einer Elektronenübertragungsschicht zwischen der zweiten leitfähigen Elektrode (4) und der EL-Schicht (6). 5
10. Berührungsanzeigevorrichtung, umfassend: eine Mehrzahl von Anzeigeelementen, angeordnet in einem Array, wobei jedes der Anzeigeelemente zumindest ein Pixelelement, umgeben mittels einer Gate-Leitung und einer Datenleitung, umfasst, und wobei die Pixelelemente das OLED gemäß einem der Ansprüche 1 bis 6 umfassen. 10
11. Berührungsanzeigevorrichtung gemäß Anspruch 10, außerdem umfassend: eine Mehrzahl von parallel zueinander angeordneten ersten Abtastleitungen (14) und eine Mehrzahl von parallel zueinander angeordneten zweiten Abtastleitungen (15), wobei die ersten Abtastleitungen (14) und die zweiten Abtastleitungen (15) sich schneiden aber nicht miteinander elektrisch verbunden sind, wobei die erste Signalelektrode (16) des OLEDs elektrisch mit den ersten Abtastleitungen (14) verbunden ist und wobei die zweite Signalelektrode (17) des OLEDs elektrisch mit den zweiten Abtastleitungen (15) verbunden ist. 15 20 25
12. Berührungsanzeigevorrichtung gemäß Anspruch 11, wobei die ersten Abtastleitungen (14) in der gleichen Schicht wie die Datenleitung sind und wobei die zweiten Abtastleitungen (15) in der gleichen Schicht wie die Gate-Leitung sind. 30
13. Berührungsanzeigevorrichtung gemäß Anspruch 11, wobei die ersten Abtastleitungen (14) in der gleichen Schicht wie die Gate-Leitung sind und wobei die zweiten Abtastleitungen (15) in der gleichen Schicht wie die Datenleitung sind. 35 40
14. Verfahren zur Herstellung einer Berührungsanzeigevorrichtung, umfassend:
 Bilden eines metallischen leitfähigen Films auf einem Substrat (11) und Bilden einer Gate-Elektrode, einer Gate-Leitung und einer längs verlaufenden Abtastleitung durch einen Bemusterungsprozess;
 Bilden einer das Substrat (11) überlagernden Gate-Isolierschicht (12),
 Bilden einer aktiven Schicht auf der Gate-Isolierschicht (12);
 Bilden eines metallischen leitfähigen Films auf dem Substrat (11) und Bilden einer Source-Elektrode, einer Drain-Elektrode, einer Datenleitung und einer quer verlaufenden Abtastleitung durch einen Bemusterungsprozess;
 Bilden einer das Substrat (11) überlagernden Passivierungsschicht (13);
 Bilden von Durchgangsöffnungen, die durch die Passivierungsschicht (13) oberhalb der Drain-Elektrode, der quer verlaufenden Abtastleitung und der längs verlaufenden Abtastleitung hindurch gehen;
 Bilden eines ersten leitfähigen Films auf der Passivierungsschicht (13) und Bilden einer Pixelelektrode, funktionierend als eine erste leitfähige Elektrode sowie als eine Signalelektrode (16) und eine zweite Signalelektrode (17, durch einen einzelnen Bemusterungsprozess, wobei die Pixelelektrode an die Drain-Elektrode elektrisch durch die Durchgangsöffnung oberhalb der Drain-Elektrode angeschlossen ist, wobei die erste Signalelektrode (16) elektrisch an die quer verlaufende Abtastleitung durch die Durchgangsöffnung oberhalb der quer verlaufenden Abtastleitung angeschlossen ist und wobei die zweite Signalelektrode (17) elektrisch an die längs verlaufende Abtastleitung durch die Durchgangsöffnung oberhalb der längs verlaufenden Abtastleitung angeschlossen ist;
 Bilden einer die Pixelelektrode sowie die erste Signalelektrode (16) und die zweite Signalelektrode (17) überlagernden isolierenden Schicht;
 Bilden einer Durchgangsöffnung in der isolierenden Schicht oberhalb der Pixelelektrode;
 Bilden einer Elektrolumineszenz-Schicht (EL) (6) in der Durchgangsöffnung, so dass eine laminierte Schicht der EL-Schicht (6) und der Pixelelektrode (2) in der gleichen Schicht wie die isolierende Schicht (15) ist und dass eine obere Oberfläche der EL-Schicht (6) bei dem gleichen Niveau wie eine obere Oberfläche der isolierenden Schicht (5) ist;
 Bilden einer die EL-Schicht und die isolierende Schicht überlagernden zweiten leitfähigen Films, wobei der zweite leitfähige Film als eine zweite leitfähige Elektrode wirkt;
 Bilden einer zumindest die zweite leitfähige Elektrode überlagernden abkapselnden Schicht. 45 50
15. Verfahren gemäß Anspruch 14, außerdem umfassend: Durchführen eines Bemusterungsprozesses auf der zweiten leitfähigen Elektrode, um den Bereich der zweiten leitfähigen Elektrode, der direkt oberhalb der ersten Signalelektrode und der zweiten Signalelektrode lokalisiert ist, zu entfernen. 55
16. Verfahren gemäß Anspruch 14 oder 15, außerdem umfassend:
 Bilden einer Lochübertragungsschicht zwischen der ersten leitfähigen Elektrode und der EL-Schicht; und
 Bilden einer Elektronenübertragungsschicht

zwischen der zweiten leitfähigen Elektrode und der EL-Schicht.

Revendications

1. Une diode électroluminescente organique, comprenant :

un substrat (1) ;
 une électrode de pixel (2) fonctionnant comme une première électrode conductrice sur le substrat (1) ;
 une première électrode de signal (3) et une deuxième électrode de signal (4) disposées sur la même couche que l'électrode de pixel (2) ;
 une couche isolante (5) recouvrant la première électrode de signal (3) et la deuxième électrode de signal (4) ;
 une couche électroluminescente (EL) (6) recouvrant l'électrode de pixel (2), une couche stratifiée comprenant la couche EL (6) et l'électrode de pixel (2) étant dans la même couche que la couche isolante (5) ;
 une deuxième électrode conductrice (7) recouvrant au moins la couche EL (6) ; et
 une couche d'encapsulation (8) recouvrant au moins la deuxième électrode conductrice (7) ;
caractérisé en ce qu'une surface supérieure de la couche EL (6) est à la même hauteur qu'une surface supérieure de la couche isolante (5).

2. La diode électroluminescente organique de la revendication 1, dans laquelle la première électrode conductrice (3) est une anode de la diode électroluminescente organique, et la deuxième électrode conductrice (4) est une cathode de la diode électroluminescente organique.

3. La diode électroluminescente organique de la revendication 2, comprenant en outre une couche de transmission de trous disposée entre l'anode et la couche EL (6).

4. La diode électroluminescente organique de la revendication 2, comprenant en outre une couche de transmission d'électrons disposée entre la cathode et la couche EL (6).

5. La diode électroluminescente organique de la revendication 1, dans laquelle la couche isolante (5) est une couche isolante organique.

6. La diode électroluminescente organique de l'une quelconque des revendications 1 à 5, dans laquelle une partie de la deuxième électrode conductrice (7) située directement au-dessus de la première élec-

trode de signal (3) et de la deuxième électrode de signal (4) est enlevée de manière que la couche d'encapsulation (8) puisse être formée directement sur le film isolant (5) au-dessus de la première électrode de signal (3) et de la deuxième électrode de signal (4).

7. Un procédé de fabrication d'une diode électroluminescente organique, comprenant :

la formation d'un premier film conducteur sur un substrat (1) ;
 la formation d'une électrode de pixel (2), ainsi que d'une première électrode de signal (3) et d'une deuxième électrode de signal (4) par un seul processus de structuration, dans lequel l'électrode de pixel (2) fonctionne comme première électrode conductrice ;
 la formation d'une couche isolante (5) recouvrant l'électrode de pixel (2), ainsi que la première électrode de signal (3) et la deuxième électrode de signal (4) ;
 la formation d'un trou d'interconnexion dans la couche isolante (5) au-dessus de l'électrode de pixel (2) ;
 la formation d'une couche électroluminescente (EL) (6) dans le trou d'interconnexion de manière qu'une couche stratifiée comprenant la couche EL (6) et l'électrode de pixel (2) soit dans la même couche que la couche isolante (5) ;
 la formation d'un deuxième film conducteur recouvrant la couche EL (6) et la couche isolante (5), le deuxième film conducteur fonctionnant comme deuxième électrode conductrice (7) ;
 la formation d'une couche d'encapsulation (8) recouvrant au moins la deuxième électrode conductrice (7) ;
caractérisé en ce qu'une surface supérieure de la couche EL (6) est à la même hauteur qu'une surface supérieure de la couche isolante (5).

8. Le procédé de la revendication 7, comprenant en outre : la réalisation d'un processus de formation de motifs sur la deuxième électrode conductrice (7) pour enlever la partie de la deuxième électrode conductrice (7) située directement au-dessus de la première électrode de signal (3) et de la deuxième électrode de signal (4) .

9. Le procédé de la revendication 7 ou 8, comprenant en outre : la formation d'une couche de transmission de trous entre la première électrode conductrice (3) et la couche EL (6), et la formation d'une couche de transmission d'électrons entre la deuxième électrode conductrice (4) et la couche EL (6).

10. Un dispositif d'affichage tactile comprenant :

une pluralité d'éléments d'affichage disposés en une matrice, dans lequel chacun des éléments d'affichage comprend un élément de pixel entouré par une ligne de grille et une ligne de données, et les éléments de pixel comprennent la DELO de l'une quelconque des revendications 1 à 6.

- 5
11. Le dispositif d'affichage tactile de la revendication 10, comprenant en outre : une pluralité de premières lignes de détection (14) disposées parallèlement les unes aux autres et une pluralité de deuxièmes lignes de détection (15) disposées parallèlement les unes aux autres, les premières lignes de détection (14) et les deuxièmes lignes de détection (15) se croisent les unes les autres mais ne sont pas électriquement reliées entre elles, la première électrode de signal (16) de la DELO est reliée électriquement aux premières lignes de détection (14), la deuxième électrode de signal (17) de la DELO est reliée électriquement aux deuxièmes lignes de détection (15).
- 10
12. Le dispositif d'affichage tactile de la revendication 11, dans lequel les premières lignes de détection (14) se trouvent dans la même couche que la ligne de données, les deuxièmes lignes de détection (15) se trouvent dans la même couche que la ligne de grille.
- 15
13. Le dispositif d'affichage tactile de la revendication 11, dans lequel les premières lignes de détection (14) se trouvent dans la même couche que la ligne de grille, les deuxièmes lignes de détection (15) se trouvent dans la même couche que la ligne de données.
- 20
14. Un procédé de fabrication d'un dispositif d'affichage tactile comprenant :

la formation d'un film métallique conducteur sur un substrat (11) et la formation d'une électrode de grille, d'une ligne de grille et d'une ligne de détection longitudinale par un processus de structuration ;

la formation d'une couche isolante de grille (12) recouvrant le substrat (11) ;

la formation d'une couche active sur la couche isolante de grille (12) ;

la formation d'un film métallique conducteur sur le substrat (11) et la formation d'une électrode de source, d'une électrode de drain, d'une ligne de données et d'une ligne de détection transversale par un processus de structuration ;

la formation d'une couche de passivation (13) recouvrant le substrat (11) ;

la formation de trous d'interconnexion à travers la couche de passivation (13) au-dessus de l'électrode de drain, de la ligne de détection transversale et de la ligne de détection

longitudinale ;

la formation d'un premier film conducteur sur la couche de passivation (13) et la formation d'une électrode de pixel fonctionnant comme première électrode conductrice, ainsi que d'une première électrode de signal (16) et d'une deuxième électrode de signal (17) par un seul processus de structuration, dans lequel l'électrode de pixel est reliée électriquement à l'électrode de drain à travers le trou d'interconnexion au-dessus de l'électrode de drain, la première électrode de signal (16) est reliée électriquement à la ligne de détection transversale à travers le trou d'interconnexion au-dessus de la ligne de détection transversale, la deuxième électrode de signal (17) est reliée électriquement à la ligne de détection longitudinale à travers le trou traversant au-dessus de la ligne de détection longitudinale ;

la formation d'une couche isolante recouvrant l'électrode pixel, ainsi que la première électrode de signal (16) et la deuxième électrode de signal (17) ;

la formation d'un trou d'interconnexion dans la couche isolante au-dessus de l'électrode de pixel ;

la formation d'une couche électroluminescente (EL) (6) dans le trou d'interconnexion de manière qu'une couche stratifiée comprenant la couche EL (6) et l'électrode de pixel (2) se trouve dans la même couche que la couche isolante (5) et une surface supérieure de la couche EL (6) est à la même hauteur que la face supérieure de la couche isolante (5) ;

la formation d'un deuxième film conducteur recouvrant la couche EL et la couche isolante, le deuxième film conducteur fonctionnant comme deuxième électrode conductrice ;

la formation d'une couche d'encapsulation recouvrant au moins la deuxième électrode conductrice.

15. Le procédé de la revendication 14, comprenant en outre : l'exécution d'un processus de structuration sur la deuxième électrode conductrice pour enlever la partie de la deuxième électrode conductrice située directement au-dessus de la première électrode de signal et de la deuxième électrode de signal.

16. Le procédé de la revendication 14 ou 15, comprenant en outre :

la formation d'une couche de transmission de trous entre la première électrode conductrice et la couche EL ; et

la formation d'une couche de transmission d'électrons entre la deuxième électrode conductrice et la couche EL.

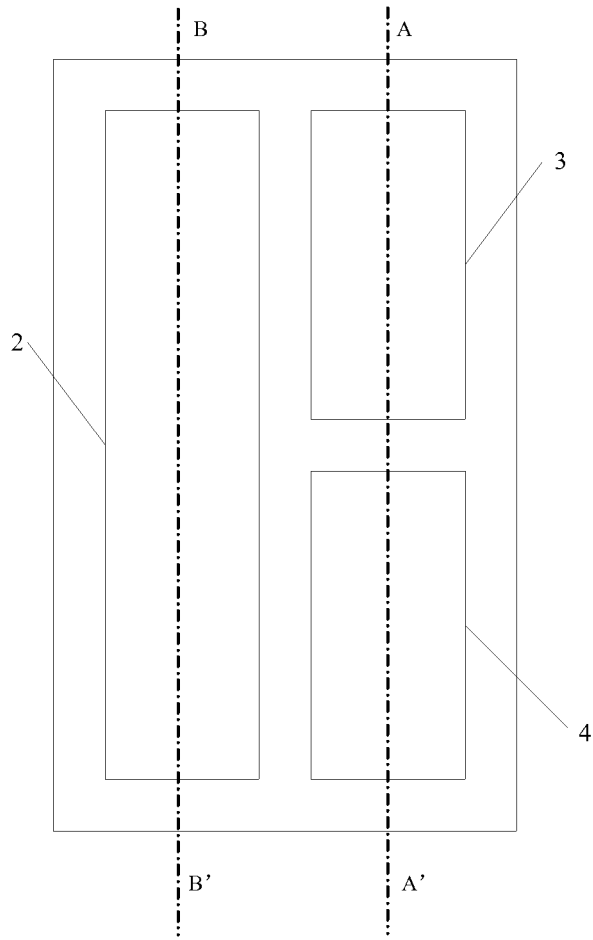


Fig.1

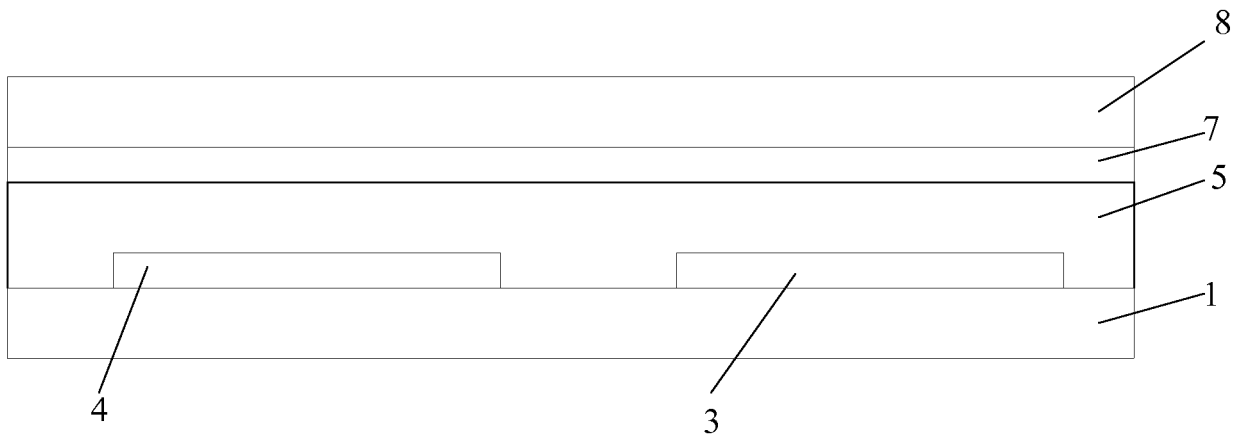


Fig.2

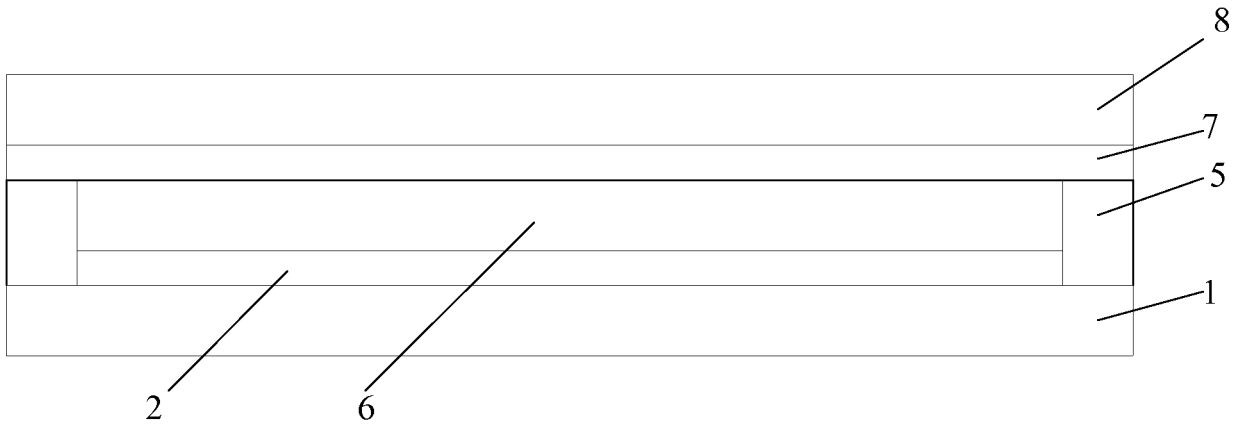


Fig.3

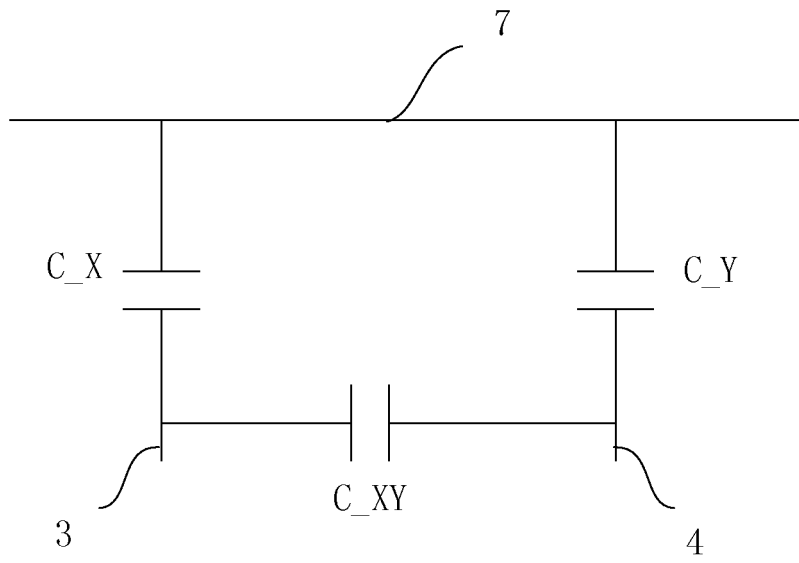


Fig.4

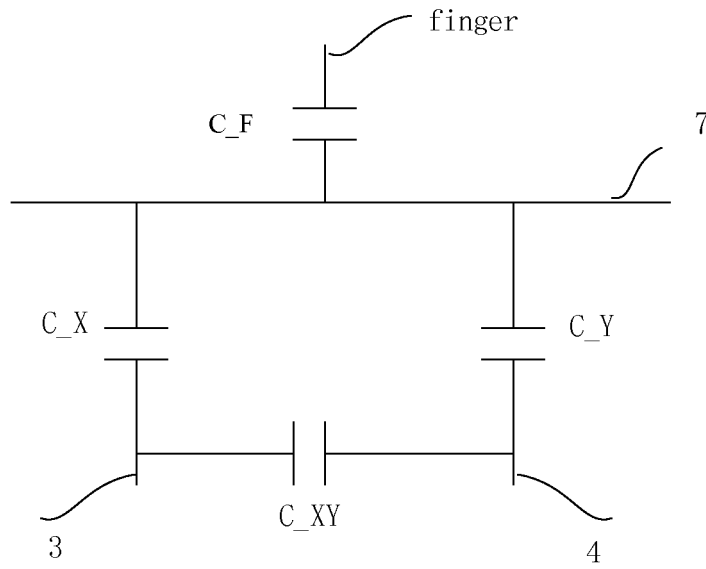


Fig.5

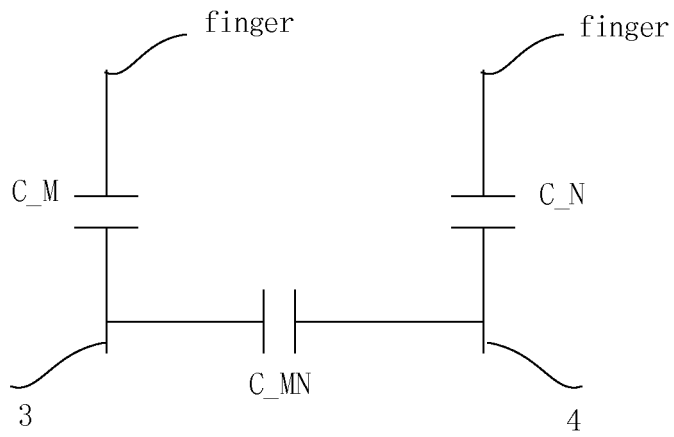


Fig.6

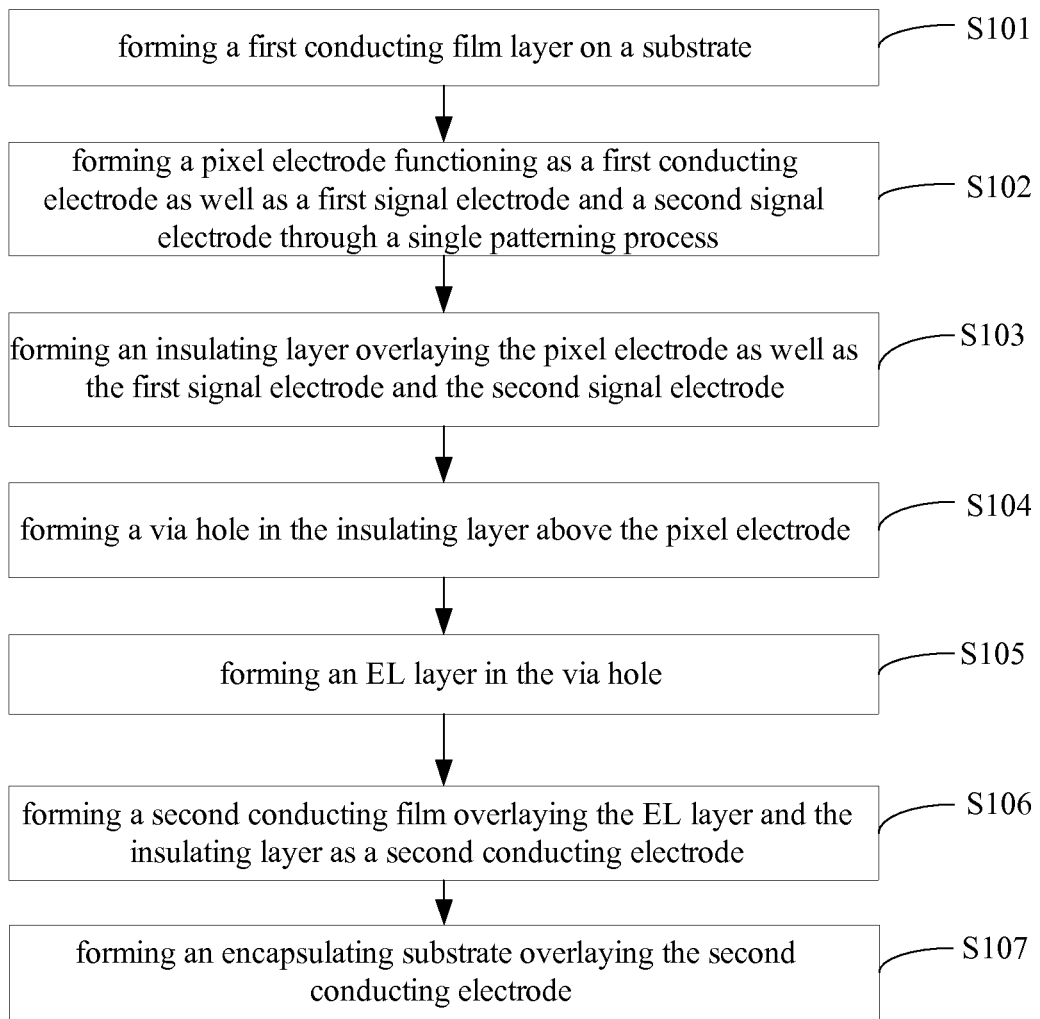


Fig.7

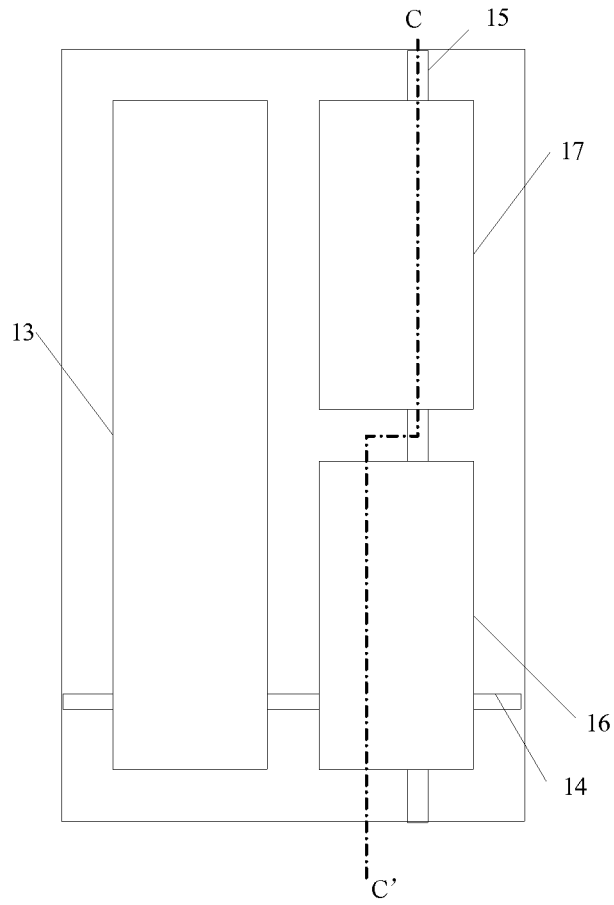


Fig.8

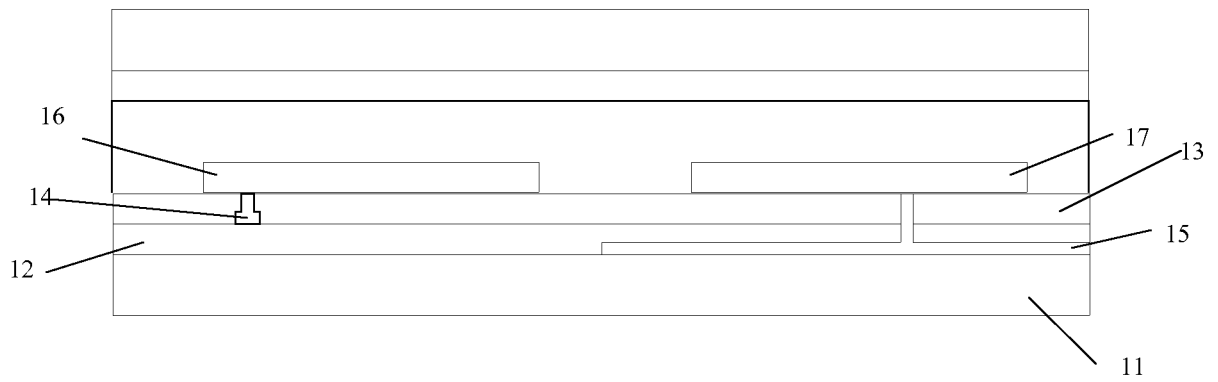


Fig.9

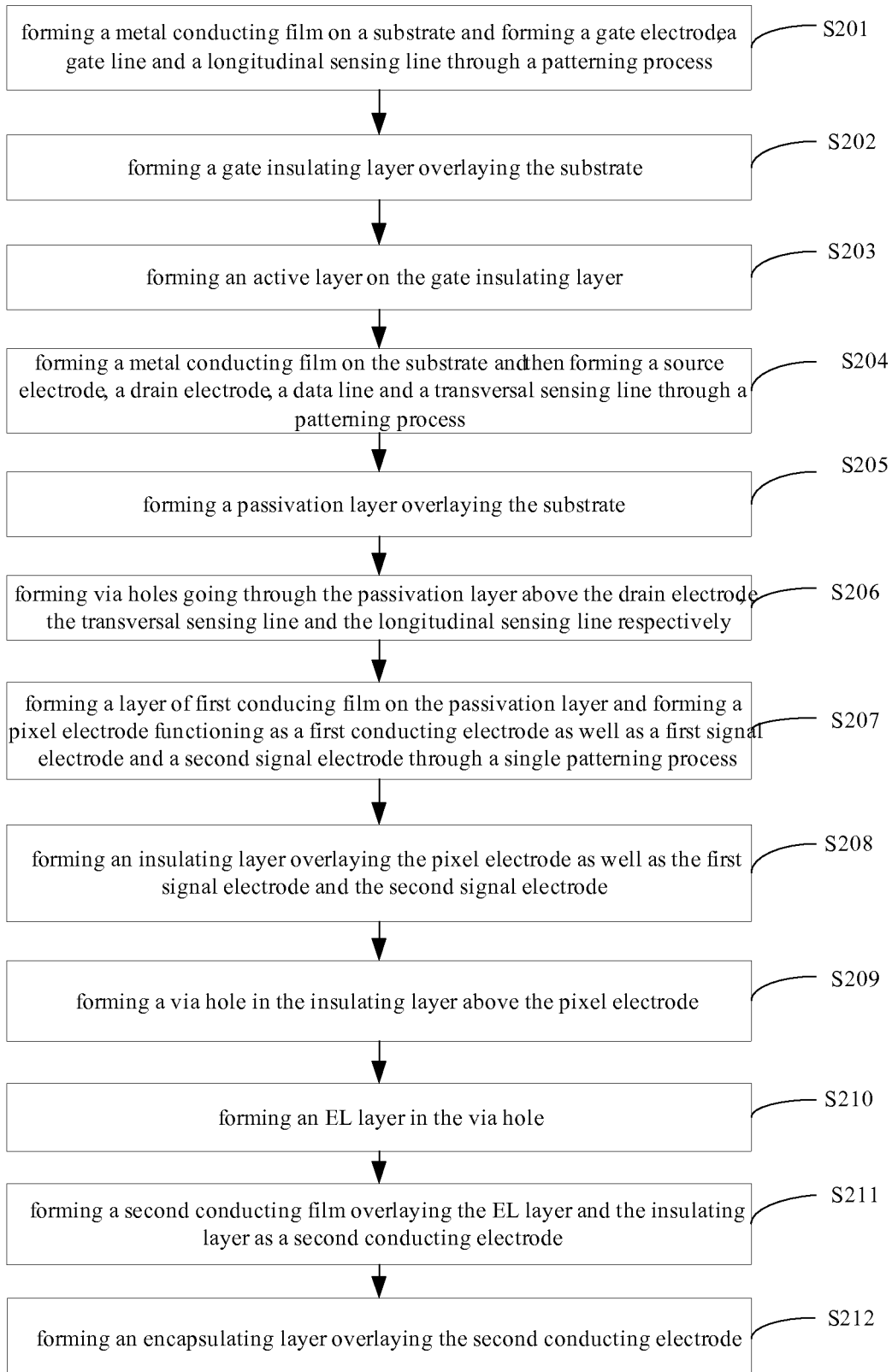


Fig.10

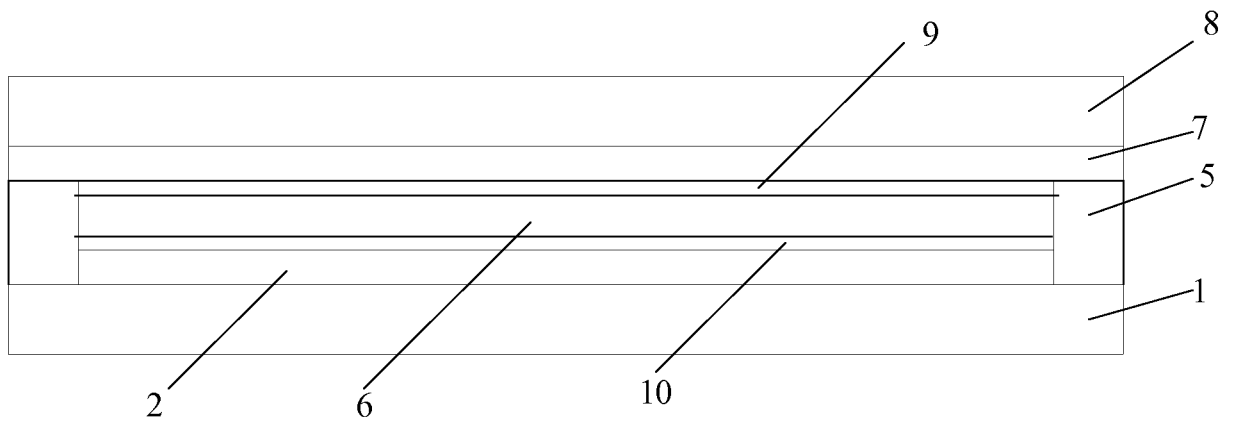


Fig.11

REFERENCES CITED IN THE DESCRIPTION

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专利名称(译)	有机发光二极管显示器，触摸显示装置及其制造方法		
公开(公告)号	EP2713400B1	公开(公告)日	2019-04-17
申请号	EP2013181566	申请日	2013-08-23
[标]申请(专利权)人(译)	京东方科技集团股份有限公司		
申请(专利权)人(译)	京东方科技集团有限公司.		
当前申请(专利权)人(译)	京东方科技集团股份有限公司.		
[标]发明人	MA ZHANJIE		
发明人	MA, ZHANJIE		
IPC分类号	H01L27/32 H03K17/96		
CPC分类号	H01L29/04 H01L27/323 H01L27/3265 H01L51/5012 H01L51/56 H03K17/962 H03K2217/960795		
优先权	201210372282.9 2012-09-28 CN		
其他公开文献	EP2713400A2 EP2713400A3		
外部链接	Espacenet		

摘要(译)

本发明提供一种OLED，触控显示装置及其制造方法。OLED包括：基板；像素电极，用作基板上的第一导电电极；第一信号电极和第二信号电极设置在与像素电极相同的层上；绝缘层，覆盖第一信号电极和第二信号电极；EL层与绝缘层位于同一层并覆盖像素电极；第二导电电极至少覆盖EL层；和至少覆盖第二导电电极的封装层。

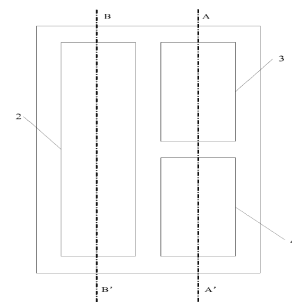


Fig. 1

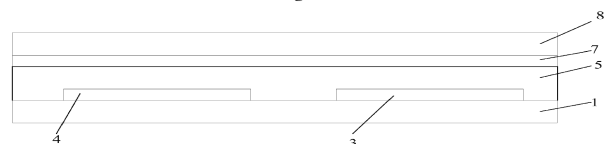


Fig. 2